

**WHAT IS CLAIMED IS:**

1                   1.       A method for forming a dense composite of silicon nitride and silicon  
2 carbide, said method comprising:

3                   (a) mechanically activating a powder mixture of amorphous silicon nitride  
4 and silicon carbide in the presence of at most 1% by weight of metal oxide  
5 densification aids, said powder mixture consisting essentially of particles less than  
6 100 nanometers in diameter; and

7                   (b) consolidating said powder mixture into a continuous mass by compressing  
8 said powder mixture while passing an electric current through said powder mixture, to  
9 achieve a fused mass of silicon nitride and silicon carbide crystals.

1                   2.       The method of claim 1 in which said mechanically activated powder  
2 mixture resulting from step (a) consists essentially of particles of about 1 micron to about 10  
3 microns in diameter, and said fused mass produced in step (b) consists essentially of  
4 crystalline grains less than 100 nm in diameter.

1                   3.       The method of claim 1 in which said mechanically activated powder  
2 mixture resulting from step (a) consists essentially of particles of about 1 micron to about 5  
3 microns in diameter, and said fused mass produced in step (b) consists essentially of  
4 crystalline grains less than 50 nm in diameter.

1                   4.       The method of claim 1 in which any metal oxide densification aid  
2 present in said powder mixture constitutes at most about 0.5% by weight of said powder  
3 mixture.

1                   5.       The method of claim 1 in which any metal oxide densification aid  
2 present in said powder mixture constitutes at most about 0.1% by weight of said powder  
3 mixture.

1                   6.       The method of claim 1 in which said powder mixture is devoid of  
2 metal oxide densification aids.

1                   7.       The method of claim 1 in which said powder mixture consists  
2 essentially of from about 10 to about 60 parts by volume silicon, from about 10 to about 60

3 parts by volume carbon, and from about 10 to about 60 parts by volume nitrogen, based on a  
4 total of 100 parts by volume of said powder mixture.

1                   8.       The method of claim 1 in which said powder mixture consists  
2 essentially of from about 10 to about 30 parts by volume silicon, from about 25 to about 50  
3 parts by volume carbon, and from about 25 to about 50 parts by volume nitrogen, based on a  
4 total of 100 parts by volume of said powder mixture.

1                   9.       The method of claim 1 further comprising forming said powder  
2 mixture by pyrolysis of a polyorganosilazane in an inert atmosphere.

1                   10.      The method of claim 9 in which said polyorganosilazane is a  
2 polyureasilazane.

1                   11.      The method of claim 1 in which step (b) comprises compressing said  
2 powder mixture at a pressure of about 10 MPa to about 200 MPa and a temperature of from  
3 about 900°C to about 3,000°C, and said electric current is a pulsed direct current of about  
4 1,000 A/cm<sup>2</sup> to about 10,000 A/cm<sup>2</sup>.

1                   12.      The method of claim 11 in which said pressure is about 40 MPa to  
2 about 100 MPa.

1                   13.      The method of claim 11 in which said temperature is about 1,000°C to  
2 about 2,000°C.

1                   14.      The method of claim 11 in which said pulsed direct current is about  
2 1,500 A/cm<sup>2</sup> to about 5,000 A/cm<sup>2</sup>.

1                   15.      The method of claim 1 in which step (b) is performed to achieve a  
2 fused mass with a density of at least 95% relative to a volume-averaged theoretical density.

1                   16.      The method of claim 1 in which step (b) is performed to achieve a  
2 fused mass with a density of at least 98% relative to a volume-averaged theoretical density.

1                   17.      The method of claim 1 in which step (b) is performed to achieve a  
2 fused mass with a density of at least 99% relative to a volume-averaged theoretical density.

1                   **18.**     The method of claim 1 in which step (a) comprises milling said powder  
2 mixture by high-energy ball milling.

1                   **19.**     The method of claim 18 in which said high-energy ball milling is  
2 performed with silicon nitride milling balls in a rotary mill at about 6 impacts per second or  
3 more and a charge ratio of at least about 10.

1                   **20.**     The method of claim 18 in which said high-energy ball milling is  
2 performed with silicon nitride milling balls in a rotary mill at from about 6 to about 60  
3 impacts per second and a charge ratio of about 10 to about 20.

1                   **21.**     A dense composite of silicon nitride and silicon carbide consisting  
2 essentially of silicon nitride crystals of less than 100 nanometers in diameter and said silicon  
3 carbide crystals of less than 100 nanometers in diameter and containing at most 1% by weight  
4 of metal oxide densification aids, produced by a process comprising:

5                   (a) mechanically activating a powder mixture of amorphous silicon nitride  
6 and silicon carbide in the presence of at most 1% by weight of metal oxide  
7 densification aids, said powder mixture consisting essentially of particles less than  
8 100 nanometers in diameter; and

9                   (b) consolidating said powder mixture into a continuous mass by compressing  
10 said powder mixture while passing an electric current through said powder mixture, to  
11 achieve a fused mass of silicon nitride and silicon carbide crystals.

1                   **22.**     The dense composite of claim 21 in which said mechanically activated  
2 powder mixture resulting from step (a) consists essentially of particles of about 1 micron to  
3 about 10 microns in diameter, and said fused mass produced in step (b) consists essentially of  
4 crystalline grains less than 100 nm in diameter.

1                   **23.**     The dense composite of claim 21 in which said mechanically activated  
2 powder mixture resulting from step (a) consists essentially of particles of about 1 micron to  
3 about 5 microns in diameter, and said fused mass produced in step (b) consists essentially of  
4 crystalline grains less than 50 nm in diameter.

1                   **24.**     The composite of claim **21** in which any metal oxide densification aid  
2 present in said powder mixture constitutes at most about 0.5% by weight of said powder  
3 mixture.

1                   **25.**     The composite of claim **21** in which any metal oxide densification aid  
2 present in said powder mixture constitutes at most about 0.1% by weight of said powder  
3 mixture.

1                   **26.**     The composite of claim **21** in which said powder mixture is devoid of  
2 metal oxide densification aids.

1                   **27.**     The composite of claim **21** in which said powder mixture consists  
2 essentially of from about 10 to about 60 parts by volume silicon, from about 10 to about 60  
3 parts by volume carbon, and from about 10 to about 60 parts by volume nitrogen, based on a  
4 total of 100 parts by volume of said powder mixture.

1                   **28.**     The composite of claim **21** said powder mixture consists essentially of  
2 from about 10 to about 30 parts by volume silicon, from about 25 to about 50 parts by  
3 volume carbon, and from about 25 to about 50 parts by volume nitrogen, based on a total of  
4 100 parts by volume of said powder mixture.

1                   **29.**     The composite of claim **21** in which said powder mixture is formed by  
2 pyrolysis of a polyorganosilazane in an inert atmosphere.

1                   **30.**     The composite of claim **29** in which said polyorganosilazane is a  
2 polyureasilazane.

1                   **31.**     The composite of claim **21** in which step (b) comprises compressing  
2 said powder mixture at a pressure of about 10 MPa to about 200 MPa and a temperature of  
3 from about 900°C to about 3,000°C, and said electric current is a pulsed direct current of  
4 about 1,000 A/cm<sup>2</sup> to about 10,000 A/cm<sup>2</sup>.

1                   **32.**     The composite of claim **31** in which said pressure is about 40 MPa to  
2 about 100 MPa.

1                   **33.**     The composite of claim **31** in which said temperature is about 1,000°C  
2 to about 2,000°C.

1                   **34.**     The composite of claim **31** in which said pulsed direct current is about  
2   1,500 A/cm<sup>2</sup> to about 5,000 A/cm<sup>2</sup>.

1                   **35.**     The composite of claim **21** in which said fused mass has a density of at  
2   least 95% relative to a volume-averaged theoretical density.

1                   **36.**     The composite of claim **21** in which said fused mass has a density of at  
2   least 98% relative to a volume-averaged theoretical density.

1                   **37.**     The composite of claim **21** in which said fused mass has a density of at  
2   least 99% relative to a volume-averaged theoretical density.

1                   **38.**     The composite of claim **21** in which step (a) comprises milling said  
2   powder mixture by high-energy ball milling.

1                   **39.**     The composite of claim **38** in which said high-energy ball milling is  
2   performed with silicon nitride milling balls in a rotary mill at about 6 impacts per second or  
3   more and a charge ratio of at least about 10.

1                   **40.**     The composite of claim **38** in which said high-energy ball milling is  
2   performed with silicon nitride milling balls in a rotary mill at about 6 to about 60 impacts per  
3   second and a charge ratio of about 10 to about 20.